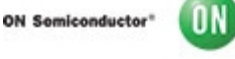


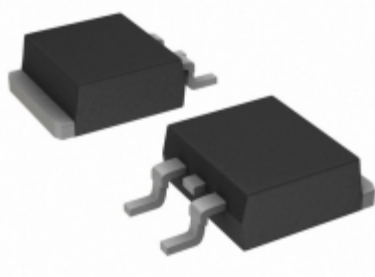


|  |  |
|--|--|
|   | <h2 style="color: #E67E22;">FQB5N90TM</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB5N90TM</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 900V 5.4A D2PAK</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQB5N90TM.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 1723 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
|   |  |
| <p>Image may be representation.<br/>See specs for product details.</p>   |  |

### Spezifikationen

|   |   |
|---|---|
| Teilenummer                                     | <a href="#">FQB5N90TM</a>   |
| Hersteller                                      | <a href="#">Fairchild/ON Semiconductor</a>                          |
| Beschreibung                                    | MOSFET N-CH 900V 5.4A D2PAK   |
| Kategorie                                       | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                      | 1723 pcs Stock  |
| Serie   | QFET®   |
| Technologie                                     | MOSFET (Metal Oxide)  |
| Betriebstemperatur                              | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                 | Surface Mount   |
| Verpackung / Gehäuse                            | TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB              |
| Supplier Device-Gehäuse                         | D <sup>2</sup> PAK (TO-263AB)                                       |
| Verlustleistung (max)                           | 3.13W (Ta), 158W (Tc)   |
| Typ FET   | N-Channel   |
| FET-Merkmal                                     | -   |
| Drain-Source-Spannung (Vdss)                    | 900V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 5.4A (Tc)   |
| Rds On (Max) @ Id, Vgs                          | 2.3 Ohm @ 2.7A, 10V   |
| VGS (th) (Max) @ Id                             | 5V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                    | 40nC @ 10V  |
| Eingabekapazität (Ciss) (Max) @ Vds             | 1550pF @ 25V  |
| Antriebsspannung (Max Rds On, Min Rds On)       | 10V   |
| Vgs (Max)                                       | ±30V  |
| Verpackung                                      | Tape & Reel (TR)  |



















































FQB5N90TM ist neu im Original, Suche FQB5N90TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB5N90TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB5N90TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |  |   |  |
|--|--|---|--|
| <br>Not Actual Photo<br>YIC International Co., Limited.   |  <p><b>FQB5P10TM</b><br/>Fairchild/ON Semiconductor<br/>MOSFET P-CH 100V 4.5A<br/>D2PAK</p> |  <p><b>FQB5N80TM</b><br/>AMI Semiconductor / ON<br/>Semiconductor<br/>MOSFET N-CH 800V 4.8A<br/>D2PAK</p> |  <p><b>FQB5P20TM</b><br/>AMI Semiconductor / ON<br/>Semiconductor<br/>MOSFET P-CH 200V 4.8A<br/>D2PAK</p> |
|  <p><b>FQB5N90</b><br/>FAIRCHILD<br/>FQB5N90 FAIRCHILD</p>  |  <p><b>FQB5N80TM</b><br/>Fairchild/ON Semiconductor<br/>MOSFET N-CH 800V 4.8A<br/>D2PAK</p> |  <p><b>FQB5N60TM</b><br/>Fairchild/ON Semiconductor<br/>MOSFET N-CH 600V 5A D2PAK</p>                     | <br>Not Actual Photo<br>YIC International Co., Limited.   |
|  <p><b>FQB5N90TM</b><br/>AMI Semiconductor / ON<br/>Semiconductor<br/>MOSFET N-CH 900V 5.4A<br/>D2PAK</p> |  <p><b>FQB5P10</b><br/>F<br/>FQB5P10 F</p>  |   |  |

### heiße Teile

Mehr

|  |  |   |   |  |
|--|--|---|---|--|
|  FQB4P25TM    |  FQB5N03    |  FQB5N06         |  FQB5N06C        |  FQB5N06L   |
|  FQB5N06LTM   |  FQB5N06LTM |  FQB5N06M        |  FQB5N06TM       |  FQB5N06TM  |
|  FQB5N06TM-NL |  FQB5N06TM  |  FQB5N06TM       |  FQB5N10         |  FQB5N10TM  |
|  FQB5N10TM    |  FQB5N20L   |  FQB5N30TM       |  FQB5N30TM       |  FQB5N50C   |
|  FQB5N50CF    |  FQB5N50CTM |  FQB5N50CTM      |  FQB5N60CTM      |  FQB5N60CTM |
|  FQB5N90TM    |  FQB5P10TM  |  FQB5P10TM       |  FQB630TM        |  FQB630TM   |
|  FQB65N06     |  FQB65N06TM |  FQB65N06TM      |  FQB6N40C        |  FQB6N40CF  |
|  FQB6N40CTM   |  FQB6N40CTM |  FQB6N50TM       |  FQB6N50TM       |  FQB6N60C   |
|  FQB6N60CTM   |  FQB6N60CTM |  FQB6N60TM       |  FQB6N60TM       |  FQB6N70TM  |
|  FQB6N70TM    |  FQB6N90TM  |  FQB6N90TM_AM002 |  FQB6N90TM_AM002 |  FQB7042FB  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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